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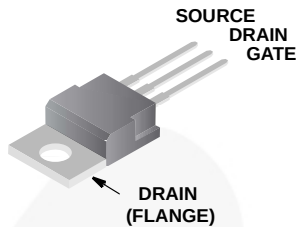
Please note. As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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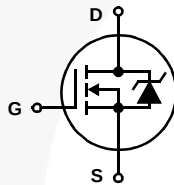
N-Channel UltraFET Power MOSFET
150 V, 43 A, 42 mΩ

Packaging

JEDEC TO-220AB



Symbol



Features

- Ultra Low On-Resistance
 - $r_{DS(ON)} = 0.042\Omega$, $V_{GS} = 10V$
- Simulation Models
 - Temperature Compensated PSPICE® and SABER™ Electrical Models
 - Spice and SABER Thermal Impedance Models
 - www.fairchildsemi.com
- Peak Current vs Pulse Width Curve
- UIS Rating Curve

Ordering Information

PART NUMBER	PACKAGE	BRAND
HUF75842P3	TO-220AB	75842P

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

	HUF75842P3	UNITS
Drain to Source Voltage (Note 1)	150	V
Drain to Gate Voltage ($R_{GS} = 20k\Omega$) (Note 1)	150	V
Gate to Source Voltage	± 20	V
Drain Current		
Continuous ($T_C = 25^\circ\text{C}$, $V_{GS} = 10V$) (Figure 2)	43	A
Continuous ($T_C = 100^\circ\text{C}$, $V_{GS} = 10V$) (Figure 2)	30	A
Pulsed Drain Current	Figure 4	
Pulsed Avalanche Rating	Figures 6, 14, 15	
Power Dissipation	230	W
Derate Above 25°C	1.53	W/ $^\circ\text{C}$
Operating and Storage Temperature	-55 to 175	$^\circ\text{C}$
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s.	300	$^\circ\text{C}$
Package Body for 10s, See Techbrief TB334.	260	$^\circ\text{C}$

NOTES:

1. $T_J = 25^\circ\text{C}$ to 150°C .

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Product reliability information can be found at <http://www.fairchildsemi.com/products/discrete/reliability/index.html>

For severe environments, see our Automotive HUFA series.

All Fairchild semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

HUF75842P3

Electrical Specifications $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
OFF STATE SPECIFICATIONS							
Drain to Source Breakdown Voltage	BV _{DSS}	I _D = 250μA, V _{GS} = 0V (Figure 11)	150	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 140V, V _{GS} = 0V	-	-	1	μA	
		V _{DS} = 135V, V _{GS} = 0V, T _C = 150°C	-	-	250	μA	
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±20V	-	-	±100	nA	
ON STATE SPECIFICATIONS							
Gate to Source Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS} , I _D = 250μA (Figure 10)	2	-	4	V	
Drain to Source On Resistance	r _{DS(ON)}	I _D = 43A, V _{GS} = 10V (Figure 9)	-	0.035	0.042	Ω	
THERMAL SPECIFICATIONS							
Thermal Resistance Junction to Case	R _{θJC}	TO-220	-	-	0.65	°C/W	
Thermal Resistance Junction to Ambient	R _{θJA}		-	-	62	°C/W	
SWITCHING SPECIFICATIONS (V _{GS} = 10V)							
Turn-On Time	t _{ON}	V _{DD} = 75V, I _D = 43A V _{GS} = 10V, R _{GS} = 3.9Ω (Figures 18, 19)	-	-	100	ns	
Turn-On Delay Time	t _{d(ON)}		-	13	-	ns	
Rise Time	t _r		-	53	-	ns	
Turn-Off Delay Time	t _{d(OFF)}		-	47	-	ns	
Fall Time	t _f		-	34	-	ns	
Turn-Off Time	t _{OFF}		-	-	120	ns	
GATE CHARGE SPECIFICATIONS							
Total Gate Charge	Q _{g(TOT)}	V _{GS} = 0V to 20V	V _{DD} = 75V, I _D = 43A, I _{g(REF)} = 1.0mA (Figures 13, 16, 17)	-	144	175	nC
Gate Charge at 10V	Q _{g(10)}	V _{GS} = 0V to 10V		-	77	90	nC
Threshold Gate Charge	Q _{g(TH)}	V _{GS} = 0V to 2V		-	5.6	6.7	nC
Gate to Source Gate Charge	Q _{gs}			-	12	-	nC
Gate to Drain "Miller" Charge	Q _{gd}			-	30	-	nC
CAPACITANCE SPECIFICATIONS							
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz (Figure 12)	-	2730	-	pF	
Output Capacitance	C _{OSS}		-	660	-	pF	
Reverse Transfer Capacitance	C _{RSS}		-	230	-	pF	

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Source to Drain Diode Voltage	V_{SD}	$I_{SD} = 43\text{A}$	-	-	1.25	V
		$I_{SD} = 22\text{A}$	-	-	1.00	V
Reverse Recovery Time	t_{rr}	$I_{SD} = 43\text{A}$, $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	190	ns
Reverse Recovered Charge	Q_{RR}	$I_{SD} = 43\text{A}$, $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	1.08	μC

Typical Performance Curves

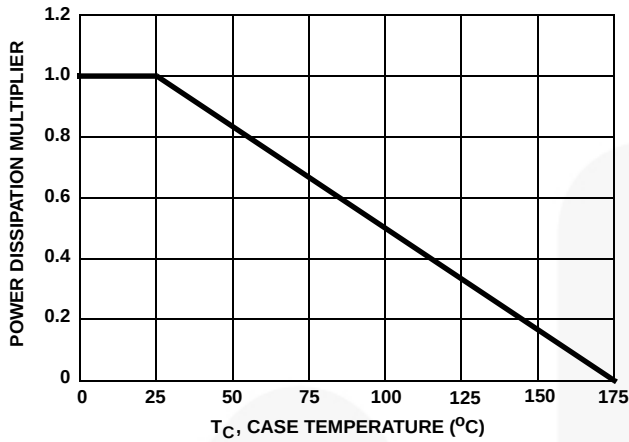


FIGURE 1. NORMALIZED POWER DISSIPATION vs CASE TEMPERATURE

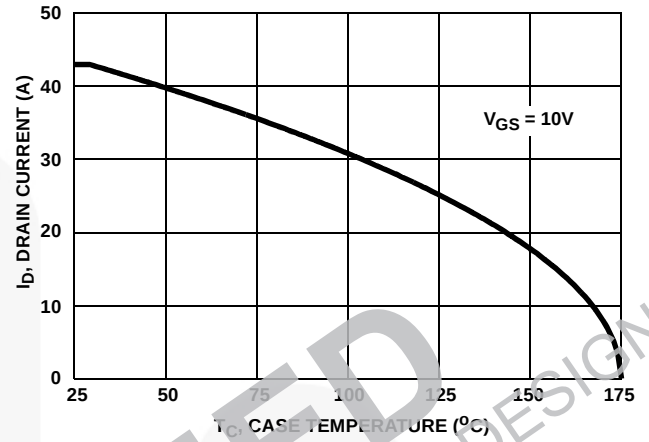


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs CASE TEMPERATURE

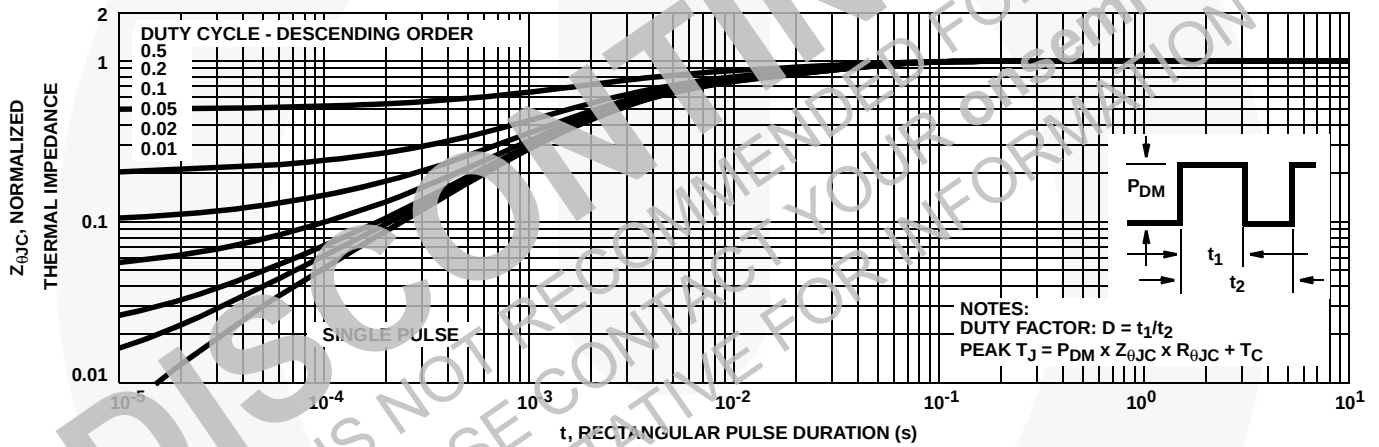


FIGURE 3. NORMALIZED MAXIMUM TRANSIENT THERMAL IMPEDANCE

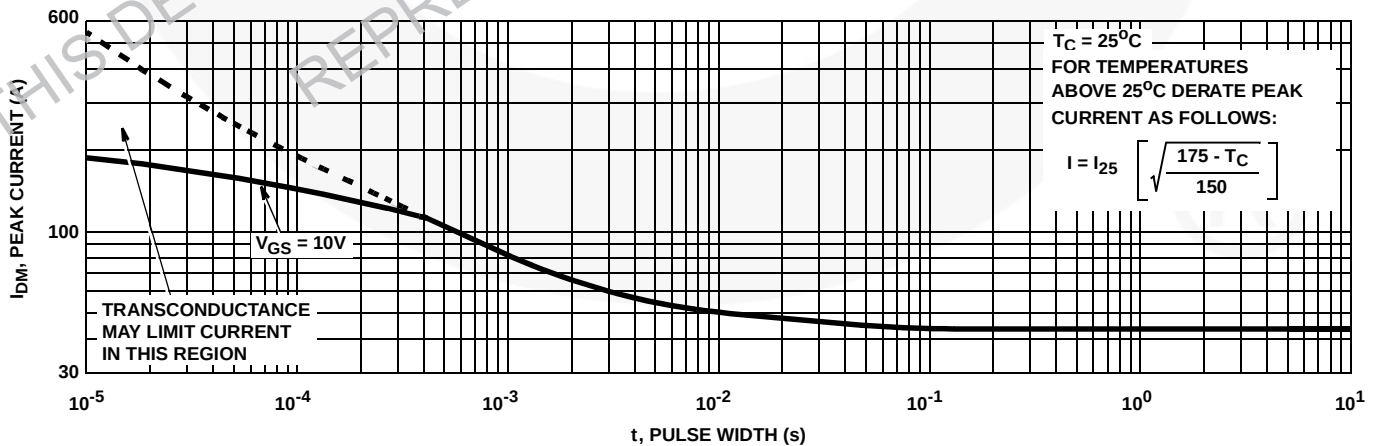


FIGURE 4. PEAK CURRENT CAPABILITY

Typical Performance Curves (Continued)

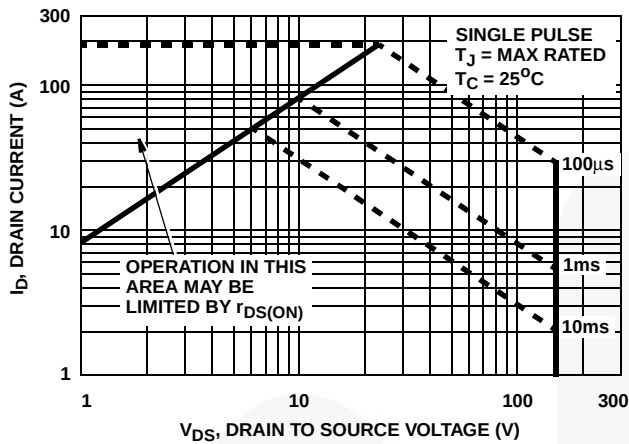
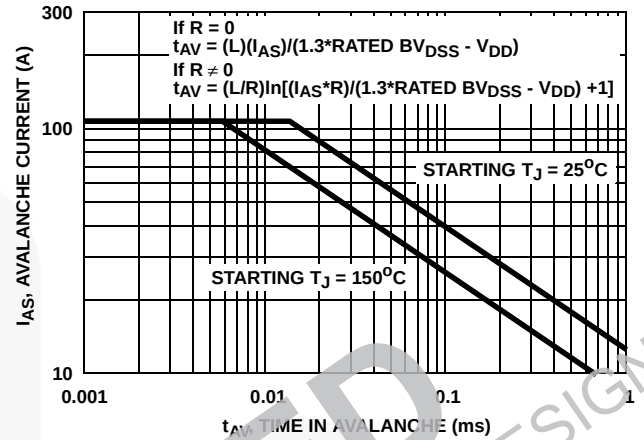


FIGURE 5. FORWARD BIAS SAFE OPERATING AREA



NOTE: Refer to Fairchild Application Notes AN9321 and AN9322.

FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING CAPABILITY

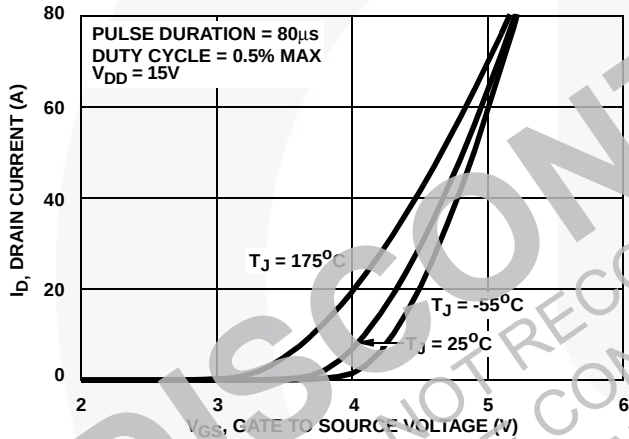


FIGURE 7. TRANSFER CHARACTERISTICS

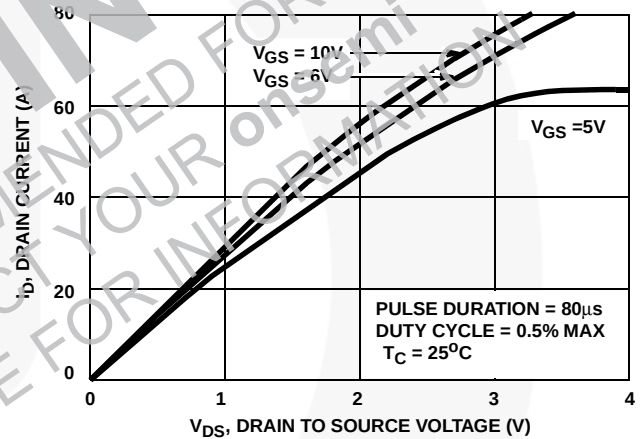


FIGURE 8. SATURATION CHARACTERISTICS

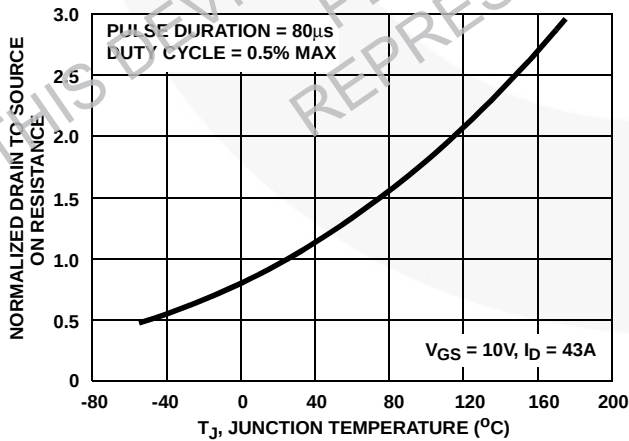


FIGURE 9. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

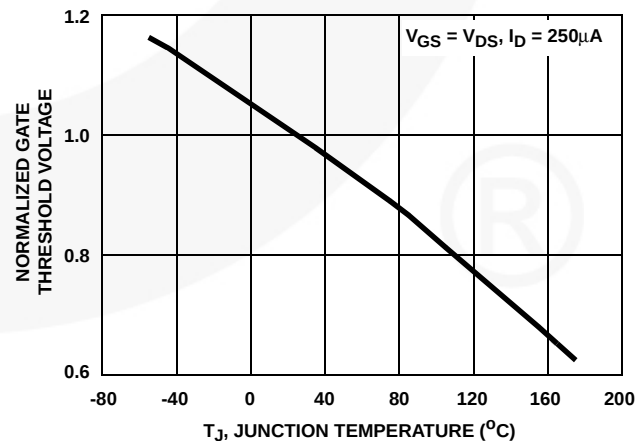


FIGURE 10. NORMALIZED GATE THRESHOLD VOLTAGE vs JUNCTION TEMPERATURE

Typical Performance Curves (Continued)

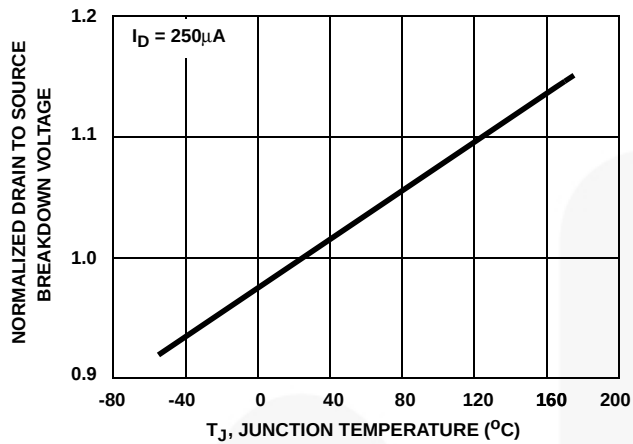


FIGURE 11. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE

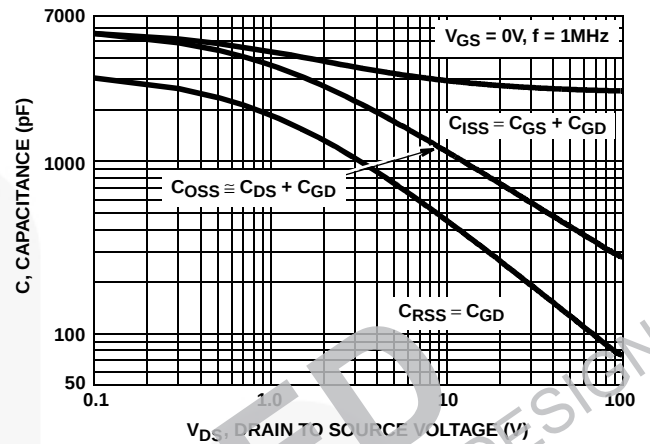
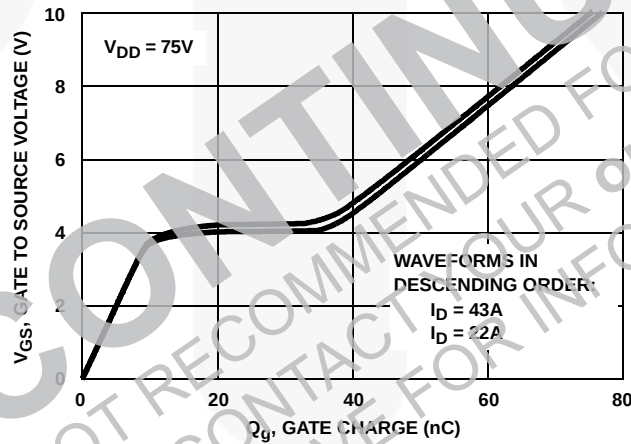


FIGURE 12. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260.

FIGURE 13. GATE CHARGE WAVEFORMS FOR CONSTANT GATE CURRENT

Test Circuits and Waveforms

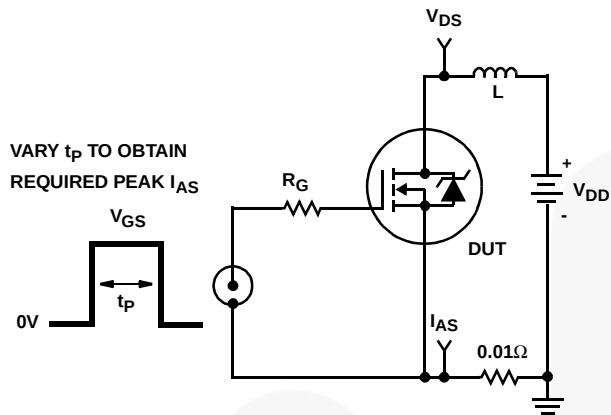


FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

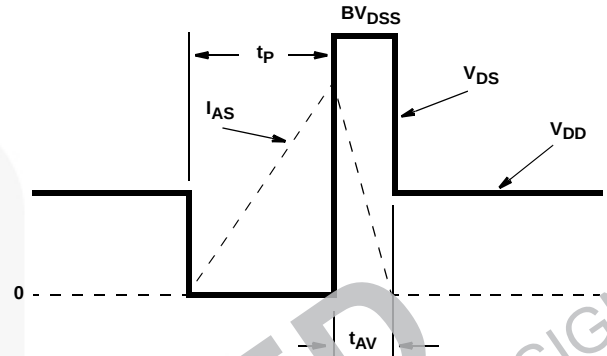


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS

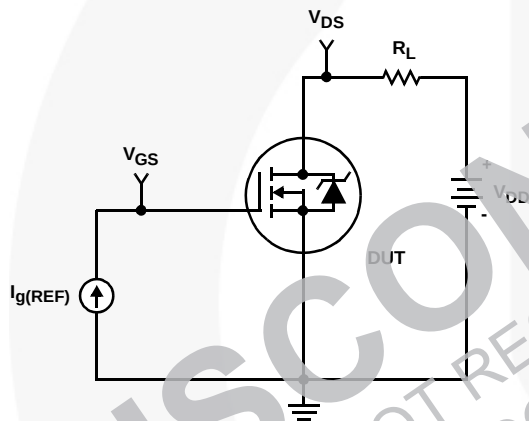


FIGURE 16. GATE CHARGE TEST CIRCUIT

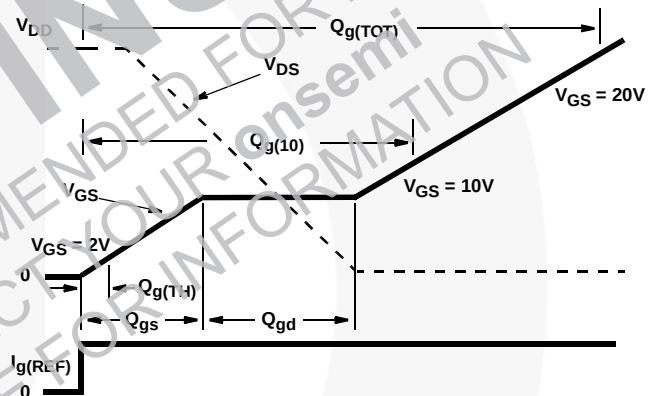


FIGURE 17. GATE CHARGE WAVEFORMS

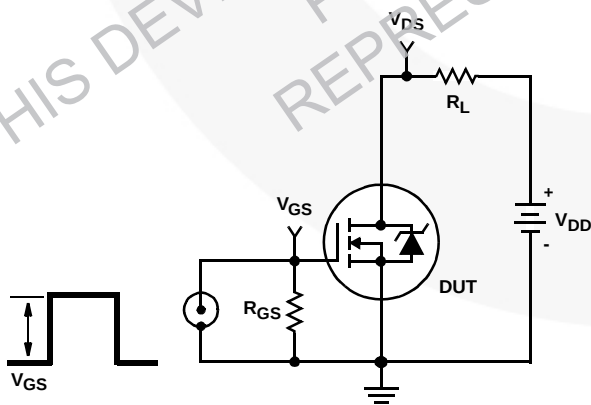


FIGURE 18. SWITCHING TIME TEST CIRCUIT

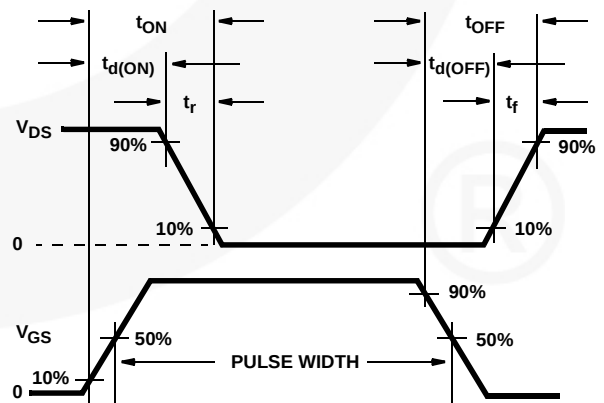


FIGURE 19. SWITCHING TIME WAVEFORM

SABER Electrical Model

REV 13 October 1999

template huf75842 n2,n1,n3

electrical n2,n1,n3

```

{
var i iscl
d..model dbodymod = (is = 2.25e-12, cjo = 2.60e-9, tt = 1.22e-7, xti = 5, m = 0.55)
d..model dbreakmod = ()
d..model dplcapmod = (cjo = 3.30e-9, is = 1e-30, m = 0.82)
m..model mmedmod = (type=_n, vto = 3.20, kp = 6, is = 1e-30, tox = 1)
m..model mstrongmod = (type=_n, vto = 3.63, kp = 86, is = 1e-30, tox = 1)
m..model mweakmod = (type=_n, vto = 2.78, kp = 0.10, is = 1e-30, tox = 1)
sw_vcsp..model s1amod = (ron = 1e-5, roff = 0.1, von = -5.8, voff = -2.4)
sw_vcsp..model s1bmod = (ron = 1e-5, roff = 0.1, von = -2.4, voff = -5.8)
sw_vcsp..model s2amod = (ron = 1e-5, roff = 0.1, von = -1.8, voff = 0.5)
sw_vcsp..model s2bmod = (ron = 1e-5, roff = 0.1, von = 0.5, voff = -1.8)

```

c.ca n12 n8 = 4.10e-9

c.cb n15 n14 = 4.10e-9

c.cin n6 n8 = 2.50e-9

d.dbody n7 n71 = model=dbodymod

d.dbreak n72 n11 = model=dbreakmod

d.dplcap n10 n5 = model=dplcapmod

i.it n8 n17 = 1

l.ldrain n2 n5 = 1e-9

l.lgate n1 n9 = 4.86e-9

l.lsource n3 n7 = 2.01e-9

m.mmed n16 n6 n8 n8 = model=mmedmod, l=1u, w=1u

m.mstrong n16 n6 n8 n8 = model=mstrongmod, l=1u, w=1u

m.mweak n16 n21 n8 n8 = model=mweakmod, l=1u, w=1u

res.rbreak n17 n18 = 1, tc1 = 1.02e-3, tc2 = 0

res.rdbody n71 n5 = 2.45e-3, tc1 = 2.70e-3, tc2 = 0

res.rdbreak n72 n5 = 6.50e-1, tc1 = 1.0e-3, tc2 = 1.0e-6

res.rdrain n50 n16 = 2.72e-2, tc1 = 9.40e-3, tc2 = 2.70e-5

res.rgate n9 n20 = 0.73

res.rldrain n2 n5 = 10

res.rlgate n1 n9 = 48.6

res.rlsource n3 n7 = 20.1

res.rslc1 n5 n51 = 1e-6, tc1 = 4.10e-3, tc2 = 4.00e-6

res.rslc2 n5 n50 = 1e3

res.rsource n8 n7 = 3.58e-3, tc1 = 1e-3, tc2 = 1e-6

res.rvtemp n18 n19 = 1, tc1 = -2.85e-3, tc2 = 3.00e-7

res.rvthres n22 n8 = 1, tc1 = -2.57e-3, tc2 = -7.05e-6

spe.ebreak n11 n7 n17 n18 = 157.5

spe.eds n14 n8 n5 n6 = 1

spe.egs n13 n8 n6 n8 = 1

spe.esg n6 n10 n6 n8 = 1

spe.evtemp n20 n6 n18 n22 = 1

spe.evthres n6 n21 n19 n8 = 1

sw_vcsp.s1a n6 n12 n13 n8 = model=s1amod

sw_vcsp.s1b n13 n12 n13 n8 = model=s1bmod

sw_vcsp.s2a n6 n15 n14 n13 = model=s2amod

sw_vcsp.s2b n13 n15 n14 n13 = model=s2bmod

v.vbat n22 n19 = dc=1

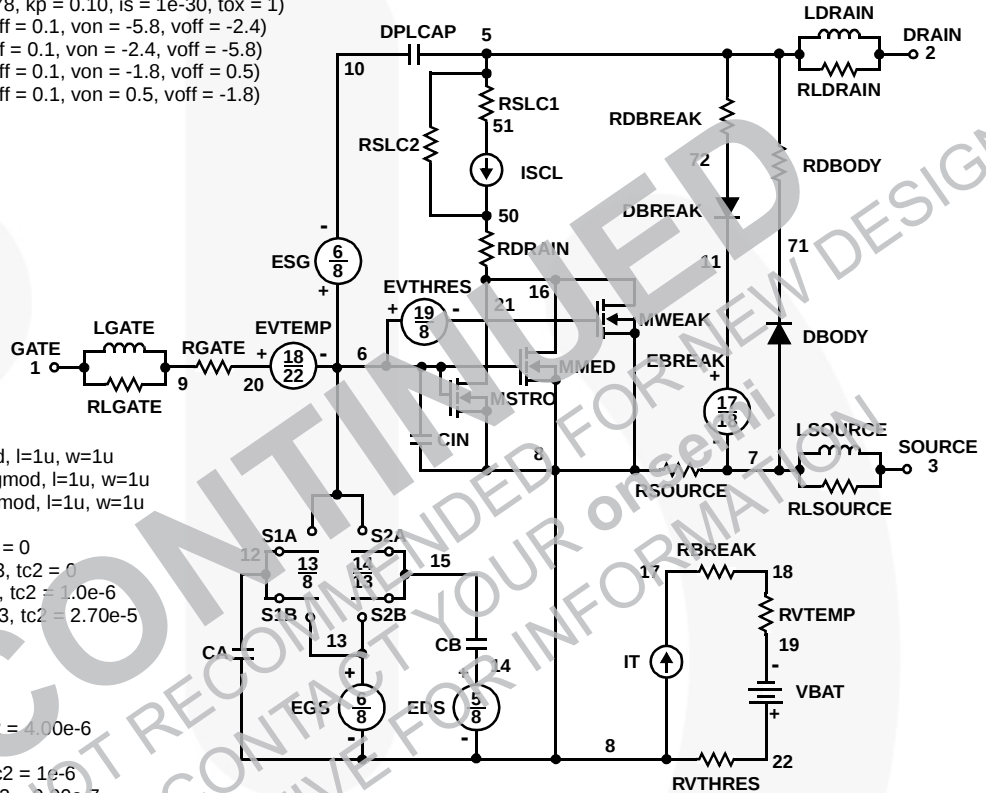
equations {

i (n51->n50) +=iscl

iscl: v(n51,n50) = (((v(n5,n51))/(1e-9+abs(v(n5,n51))))*((abs(v(n5,n51))*1e6/88))** 3.5))

}

}



SPICE Thermal Model

REV 13 October 1999

HUF75842T

CTHERM1 th 6 5.20e-3
 CTHERM2 6 5 2.40e-2
 CTHERM3 5 4 2.00e-2
 CTHERM4 4 3 1.80e-2
 CTHERM5 3 2 2.40e-2
 CTHERM6 2 tl 1.80e-1

R THERM1 th 6 1.00e-2
 R THERM2 6 5 2.00e-2
 R THERM3 5 4 6.40e-2
 R THERM4 4 3 1.00e-1
 R THERM5 3 2 1.56e-1
 R THERM6 2 tl 1.65e-1

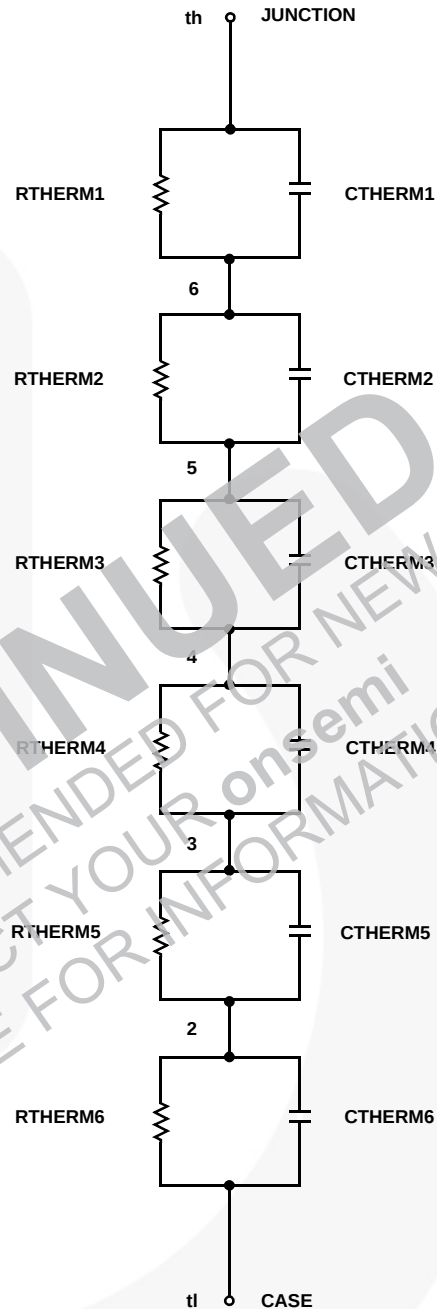
SABER Thermal Model

SABER thermal model HUF75842T

template thermal_model th tl
 thermal_c th, tl

```
{
  ctherm.ctherm1 th 6 = 5.20e-3
  ctherm.ctherm2 6 5 = 2.40e-2
  ctherm.ctherm3 5 4 = 2.00e-2
  ctherm.ctherm4 4 3 = 1.80e-2
  ctherm.ctherm5 3 2 = 2.40e-2
  ctherm.ctherm6 2 tl = 1.80e-1
```

```
rtherm.rtherm1 th 6 = 1.00e-2
rtherm.rtherm2 6 5 = 2.00e-2
rtherm.rtherm3 5 4 = 6.40e-2
rtherm.rtherm4 4 3 = 1.00e-1
rtherm.rtherm5 3 2 = 1.56e-1
rtherm.rtherm6 2 tl = 1.65e-1
}
```





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CorePOWER™	Green FPS™ e-Series™	Quiet Series™	TinyLogic®
CROSSVOLT™	Gmax™	RapidConfigure™	TINYOPTO™
CTL™	GTO™	Saving our world, 1mW/W/kW at a time™	TinyPower™
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DEUXPEED®	ISOPLANAR™	SmartMax™	TinyWire™
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EcoSPARK®	MegaBuck™	Solutions for Your Success™	TriFault Detect™
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FACT Quiet Series™	MotionMax™	SuperSOT™-8	UniFET™
FACT®	mWSaver®	SupreMOS®	VCX™
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FETBench™	OPTOPLANAR®		XS™
FPS™			

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 166

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